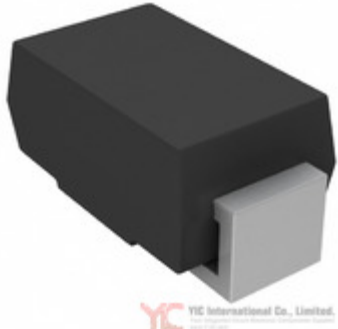
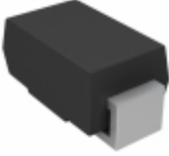
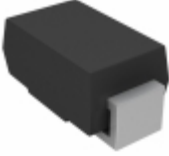
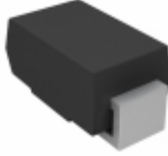
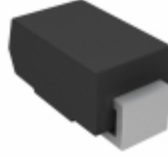
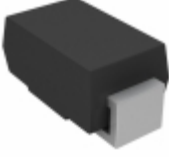
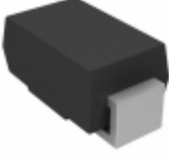


	<h2>US1K-E3/61T</h2>
	<p>Hersteller-Teilenummer: US1K-E3/61T</p> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <p>Teil der Beschreibung: DIODE GEN PURP 800V 1A DO214AC</p> <p>Datenblätter: 1.US1K-E3/61T.pdf 2.US1K-E3/61T.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 38284 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	US1K-E3/61T
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 800V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	38284 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.7V @ 1A
Strom - Sperrleckstrom @ Vr	10µA @ 800V
Spannung - Sperr (Vr) (max)	800V
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	75ns
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	10pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)

US1K-E3/61T ist neu im Original, Suche US1K-E3/61T Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie US1K-E3/61T Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage US1K-E3/61T: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>US1K-E3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 800V 1A DO214AC</p>	 <p>US1K-E3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 800V 1A DO214AC</p>	 <p>US1K-M3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 800V 1A DO214AC</p>	 <p>US1K-M3/5AT Vishay / Semiconductor - Diodes Division DIODE 1A 800V 75NS DO- 214AC</p>
 <p>US1K-M3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 800V 1A DO214AC</p>	 <p>US1K-E3/5AT Vishay / Semiconductor - Diodes Division DIODE GEN PURP 800V 1A DO214AC</p>	 <p>US1K-E3D/H Vishay Precision Group US1K-E3D/H VISHAY</p>	 <p>US1K-13-F Diodes Incorporated DIODE GEN PURP 800V 1A SMA</p>

heiße Teile

Mehr

⊗ US1D-M3/61T	↔ US1D-M3/61T	⇒ US1DWF-7	D US1DWF-7	↔ US1G-13-F
⊣ US1G-E3/61T	⊗ US1G-E3/61T	D US1G-M3/61T	⇒ US1G-M3/61T	↔ US1G/11T
⊗ US1GHE3/5AT	⊣ US1GHE3/5AT	⊗ US1GHE3/61	↔ US1GHE3/61T	↔ US1GHE3/61T
D US1GHE3_A/H	⊗ US1GHE3_A/H	⊣ US1GWF-7	⊗ US1GWF-7	↔ US1J-13-F
⇒ US1J-5AT	↔ US1J-E3/5AT	⊗ US1J-E3/5AT	⊣ US1J-E3/61T	↔ US1J-E3/61T
↔ US1J-M3/61T	⇒ US1J-M3/61T	D US1J/11T	⊗ US1J/61T	⊣ US1JE-TP
⊗ US1K-13-F	D US1K-E3/61T	⇒ US1K-E3D/H	↔ US1K-M3/5AT	↔ US1K-M3/5AT
⊣ US1K-M3/61T	⊗ US1K-M3/61T	↔ US1K/11T	⇒ US1KSAFS-13	↔ US1KSAFS-13
⊗ US1M-13-F	⊣ US1M-13-F-73	⊗ US1M-E3/61	D US1M-E3/61T	↔ US1M-E3/61T
↔ US1M-M3/5AT	⊗ US1M-M3/5AT	⊣ US1M-M3/61T	⊗ US1M-M3/61T	↔ US1M-R1-10001

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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